

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

QEC121, QEC122, QEC123 Plastic Infrared Light Emitting Diode

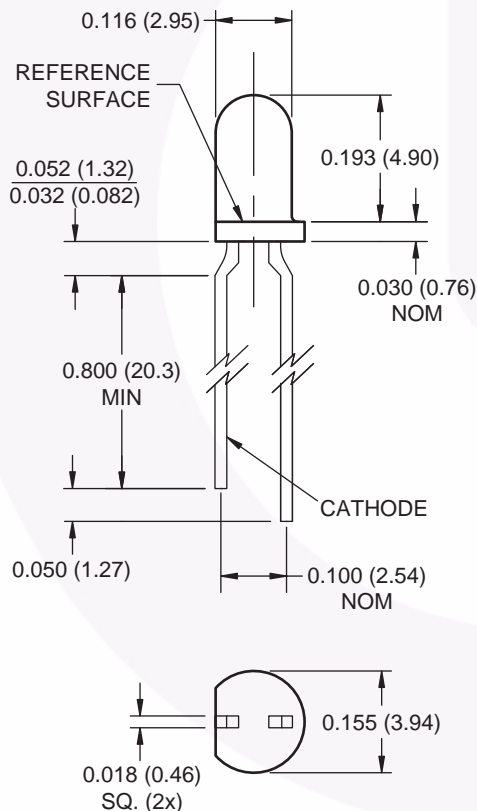
Features

- $\lambda = 880\text{nm}$
- Chip material = AlGaAs
- Package type: T-1 (3mm)
- Matched photosensor: QSC112/QSC113/QSC114
- Narrow emission angle, 8° at 80% intensity
- High output power
- Package material and color: clear, purple tinted, plastic

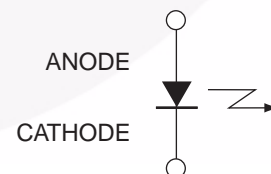
Description

The QEC121, QEC122 and QEC123 are 880nm AlGaAs LED encapsulated in a clear purple tinted, plastic T-1 package.

Package Dimensions



Schematic



Notes:

1. Dimensions of all drawings are in inches (mm).
2. Tolerance is ± 0.10 (0.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating	Units
T_{OPR}	Operating Temperature	-40 to +100	$^\circ\text{C}$
T_{STG}	Storage Temperature	-40 to +100	$^\circ\text{C}$
T_{SOL-I}	Soldering Temperature (Iron) ⁽²⁾⁽³⁾⁽⁴⁾	240 for 5 sec	$^\circ\text{C}$
T_{SOL-F}	Soldering Temperature (Flow) ⁽²⁾⁽³⁾	260 for 10 sec	$^\circ\text{C}$
I_F	Continuous Forward Current	50	mA
V_R	Reverse Voltage	5	V
P_D	Power Dissipation ⁽¹⁾	100	mW

Notes:

1. Derate power dissipation linearly 1.33mW/ $^\circ\text{C}$ above 25°C .
2. RMA flux is recommended.
3. Methanol or isopropyl alcohols are recommended as cleaning agents.
4. Soldering iron 1/16" (1.6mm) minimum from housing.

Electrical / Optical Characteristics ($T_A = 25^\circ\text{C}$)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
λ_{PE}	Peak Emission Wavelength	$I_F = 100\text{mA}$		890		nm
TC_λ	Temperature Coefficient			0.2		nm/ $^\circ\text{C}$
$2\theta^{1/2}$	Emission Angle	$I_F = 100\text{mA}$		18		$^\circ$
V_F	Forward Voltage	$I_F = 100\text{mA}$, $t_p = 20\text{ms}$			1.7	V
TC_{VF}	Temperature Coefficient			-6		mV/ $^\circ\text{C}$
I_R	Reverse Current	$V_R = 5\text{V}$			10	μA
I_E	Radiant Intensity QEC121	$I_F = 100\text{mA}$, $t_p = 20\text{ms}$	14			mW/sr
I_E	Radiant Intensity QEC122	$I_F = 100\text{mA}$, $t_p = 20\text{ms}$	27		94	mW/sr
I_E	Radiant Intensity QEC123	$I_F = 100\text{mA}$, $t_p = 20\text{ms}$	39	45		mW/sr
TC_{IE}	Temperature Coefficient			-0.3		%/ $^\circ\text{C}$
t_r	Rise Time	$I_F = 100\text{mA}$		900		ns
t_f	Fall Time			800		ns
C_j	Junction Capacitance	$V_R = 0\text{V}$		11		pF

Typical Performance Curves

Figure 1. Normalized Intensity vs. Wavelength

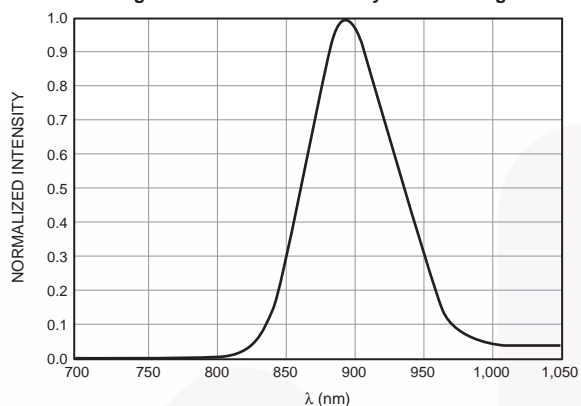


Figure 2. Peak Wavelength vs. Ambient Temperature

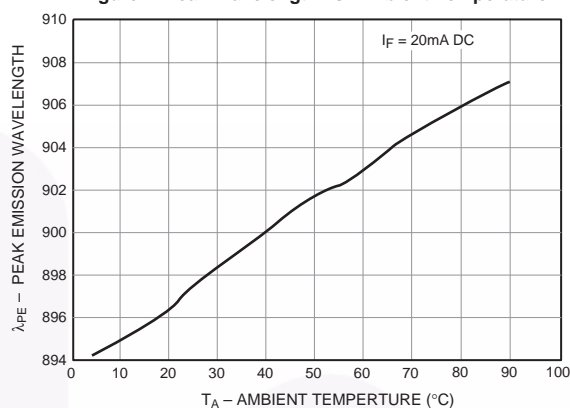


Figure 3. Normalized Radiant Intensity vs. Forward Current

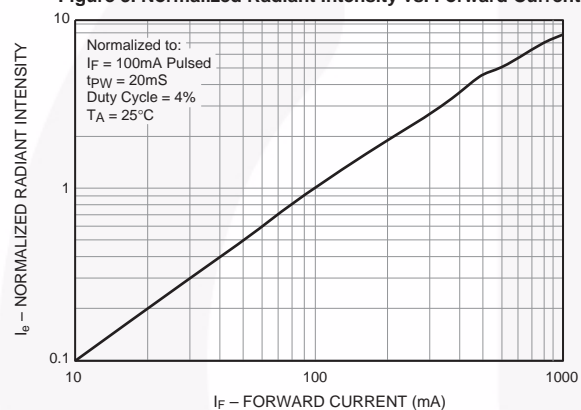


Figure 4. Normalized Radiant Intensity vs. Ambient Temperature

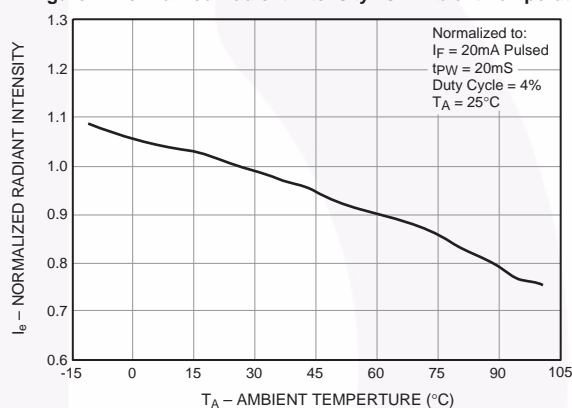


Figure 5. Forward Voltage vs. Forward Current

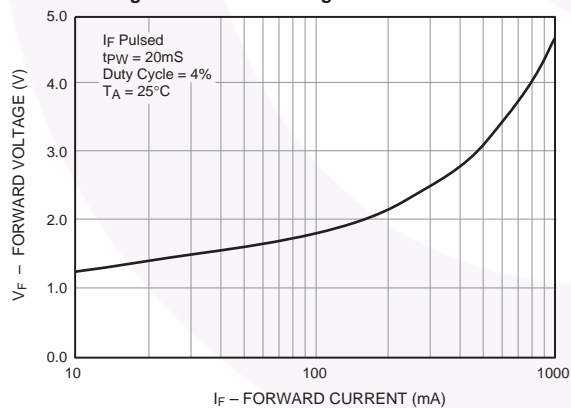
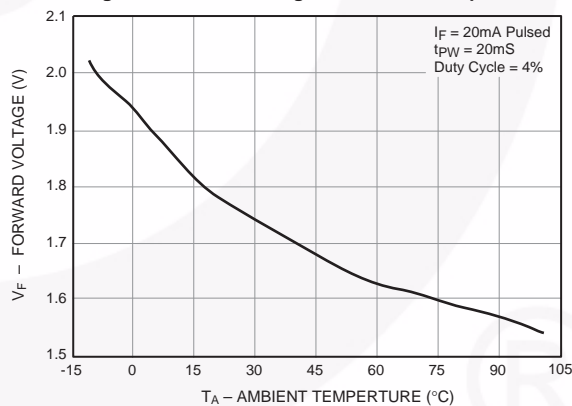


Figure 6. Forward Voltage vs. Ambient Temperature



Typical Performance Curves (Continued)

Figure 7. Radiation Diagram

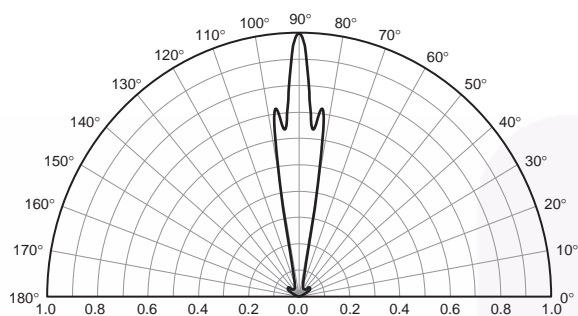
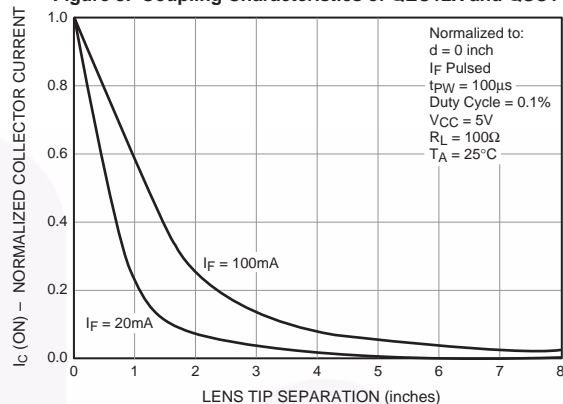








Figure 8. Coupling Characteristics of QEC12X and QSC11X





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Definition of Terms

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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